74ALVC00

Quad 2-input NAND gate

Rev. 6 — 4 July 2023

Product data sheet

1. General description

The 74ALVC00 is a quad 2-input NAND gate.

Schmitt trigger action on all inputs makes the device tolerant of slow rise and fall times.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 3.6 V
- CMOS low power dissipation
- Overvoltage tolerant inputs to 3.6 V
- · Direct interface with TTL levels
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 250 mA per JESD78 Class II.A
- · Complies with JEDEC standards:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

3. Ordering information

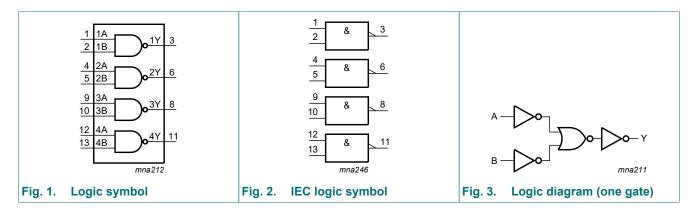
Table 1. Ordering information

Type number	Package	Package						
Temperature range Name Description		Description	Version					
74ALVC00D	-40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1				
74ALVC00PW	-40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1				
74ALVC00BQ	-40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm	SOT762-1				



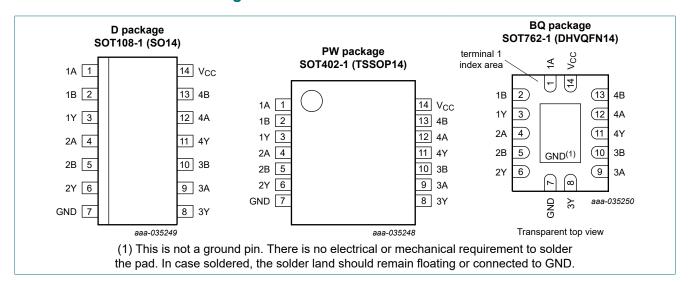
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4. Functional diagram



5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1A, 2A, 3A, 4A	1, 4, 9, 12	data input
1B, 2B, 3B, 4B	2, 5, 10, 13	data input
1Y, 2Y, 3Y, 4Y	3, 6, 8, 11	data output
GND	7	ground (0 V)
V _{CC}	14	supply voltage

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6. Functional description

Table 3. Function selection

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care.$

Input		Output
nA	nB	nY
L	X	Н
X	L	Н
Н	Н	L

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	[1]	-0.5	+4.6	V
Vo	output voltage	output HIGH or LOW state [1]	-0.5	V _{CC} + 0.5	V
		power-down mode; V _{CC} = 0 V	-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
I _{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0$ V	-	±50	mA
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±50	mA
I _{CC}	supply current		-	100	mA
I _{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}$ [2]	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		1.65	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	output HIGH or LOW state	0	V _{CC}	V
		power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature	in free air	-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 1.65 V to 2.7 V	0	20	ns/V
		V _{CC} = 2.7 V to 3.6 V	0	10	ns/V

Product data sheet

^[2] For SOT108-1 (SO14) package: Ptot derates linearly with 10.1 mW/K above 100 °C.

For SOT402-1 (TSSOP14) package: Ptot derates linearly with 7.3 mW/K above 81 °C.

For SOT762-1 (DHVQFN14) package: Ptot derates linearly with 9.6 mW/K above 98 °C.

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9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
V _{IH}	HIGH-level input	V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}	-	-	0.65 × V _{CC}	-	V
	voltage	V _{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
V_{IL}	LOW-level input	V _{CC} = 1.65 V to 1.95 V	-	-	0.35 × V _{CC}	-	0.35 × V _{CC}	V
	voltage	V _{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}						
	output voltage	I _O = -100 μA; V _{CC} = 1.65 V to 3.6 V	V _{CC} - 0.2	-	-	V _{CC} - 0.2		V
		I _O = -6 mA; V _{CC} = 1.65 V	1.25	1.51	-	1.25	-	V
		I _O = -12 mA; V _{CC} = 2.3 V	1.8	2.10	-	1.8	-	V
		I _O = -18 mA; V _{CC} = 2.3 V	1.7	2.01	-	1.7	-	V
		$I_O = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	2.53	-	2.2	-	V
		I _O = -18 mA; V _{CC} = 3.0 V	2.4	2.76	-	2.4	-	V
		I _O = -24 mA; V _{CC} = 3.0 V	2.2	2.68	-	2.2	-	V
V_{OL}	LOW-level output	V _I = V _{IH} or V _{IL}						
	voltage	I _O = 100 μA; V _{CC} = 1.65 V to 3.6 V	-	-	0.2	-	0.2	V
		I _O = 6 mA; V _{CC} = 1.65 V	-	0.11	0.3	-	0.3	V
		$I_O = 12 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	0.17	0.4	-	0.4	V
		$I_O = 18 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	0.25	0.6	-	0.6	V
		$I_O = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	0.16	0.4	-	0.4	V
		I_{O} = 18 mA; V_{CC} = 3.0 V	-	0.23	0.4	-	0.45	V
		$I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	0.30	0.55	-	0.55	V
l _l	input leakage current	V _{CC} = 3.6 V; V _I = 3.6 V or GND	-	±0.1	±5	-	±20	μΑ
I _{OFF}	power-off leakage current	$V_{CC} = 0 \text{ V};$ $V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}$	-	±0.1	±10	-	±80	μΑ
I _{CC}	supply current	V_{CC} = 3.6 V; V_I = V_{CC} or GND; I_O = 0 A	-	0.2	20	-	160	μΑ
ΔI _{CC}	additional supply current	per input pin; $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $V_1 = V_{CC} - 0.6 \text{ V};$ $I_0 = 0 \text{ A}$	-	5	750	-	750	μΑ
Cı	input capacitance		-	3.5	-	-	-	pF

^[1] All typical values are measured at V_{CC} = 3.3 V (unless stated otherwise) and T_{amb} = 25 °C.

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10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit, see Fig. 5.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation	nA, nB to nY; see Fig. 4 [2]						
	delay	V _{CC} = 1.65 V to 1.95 V	1.0	2.8	4.4	1.0	5.1	ns
		V _{CC} = 2.3 V to 2.7 V	1.0	2.1	2.8	1.0	3.2	ns
		V _{CC} = 2.7 V	1.0	2.6	3.2	1.0	3.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	2.1	3.0	1.0	3.5	ns
C _{PD}	power dissipation capacitance	per gate; V_I = GND to V_{CC} ; [3] V_{CC} = 3.3 V	-	28	-	-	-	pF

Typical values are measured at T_{amb} = 25 °C.

 t_{pd} is the same as t_{PHL} and t_{PLH} . C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

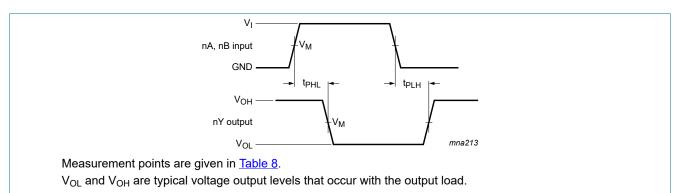
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

10.1. Waveforms and test circuit

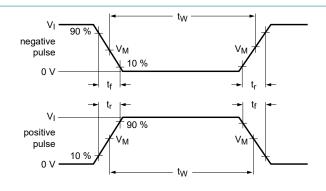


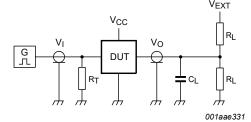
Inputs nA, nB to output nY propagation delay times

Table 8. Measurement points

Supply voltage V _{CC}	Input V _I	V _M
1.65 V to 1.95 V	V_{CC}	0.5 × V _{CC}
2.3 V to 2.7 V	V _{CC}	0.5 × V _{CC}
2.7 V	2.7 V	1.5 V
3.0 V to 3.6 V	2.7 V	1.5 V

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Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance;

 C_L = Load capacitance including jig and probe capacitance;

R_T = Termination resistance should be equal to output impedance Z_O of the pulse generator;

 V_{EXT} = External voltage for measuring switching times.

Fig. 5. Test circuit for measuring switching times

Table 9. Test data

Supply voltage	Input		Load		V _{EXT}	V _{EXT}		
V _{CC}	V _I	t _r , t _f	CL	R _L	t _{PLH} , t _{PHL}	t _{PLZ} , t _{PZL}	t _{PHZ} , t _{PZH}	
1.65 V to 1.95 V	V _{CC}	≤ 2.0 ns	30 pF	1 kΩ	open	2 × V _{CC}	GND	
2.3 V to 2.7 V	V _{CC}	≤ 2.0 ns	30 pF	500 Ω	open	2 × V _{CC}	GND	
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	6 V	GND	
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	6 V	GND	

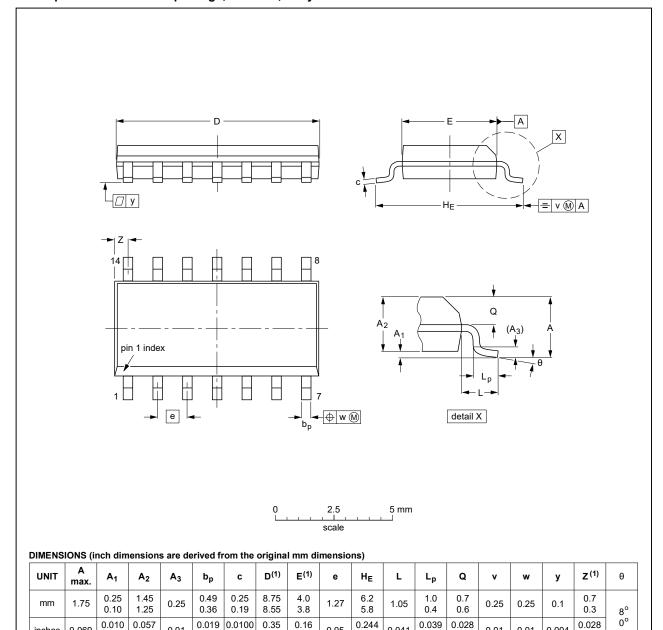
Product data sheet

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11. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



inches

0.069

0.004

0.049

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

0.014 | 0.0075

0.01

OUTLINE	UTLINE REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT108-1	076E06	MS-012				99-12-27 03-02-19

0.05

0.228

0.15

0.041

0.016

0.024

0.01

0.01

0.004

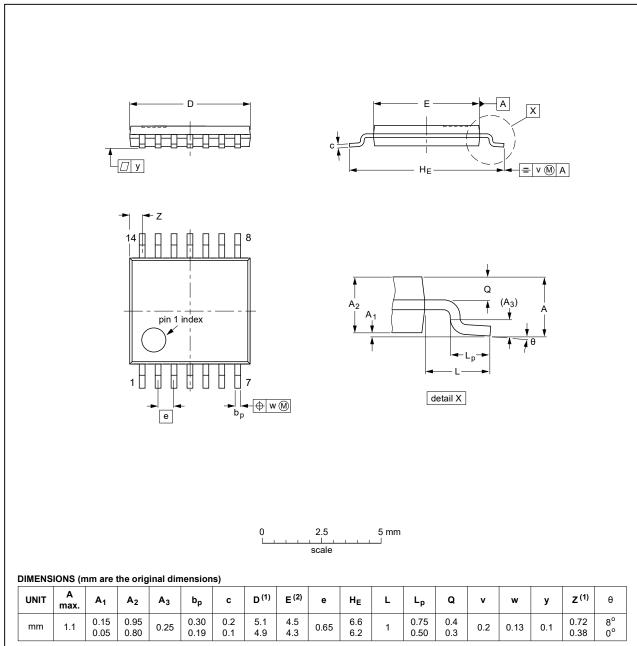
0.012

Fig. 6. Package outline SOT108-1 (SO14)

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	REFERENCES EUROPEAN IS			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT402-1		MO-153				99-12-27 03-02-18

Fig. 7. Package outline SOT402-1 (TSSOP14)

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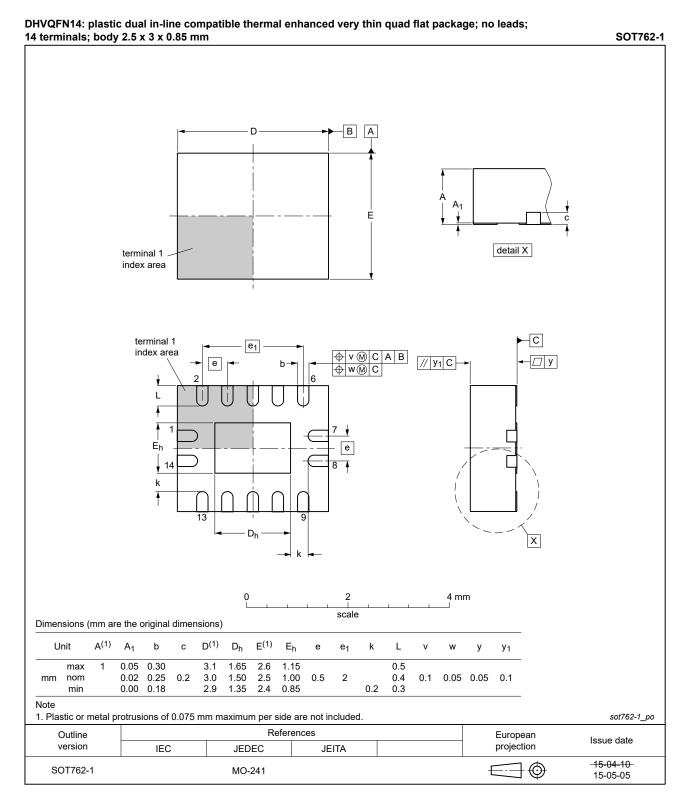


Fig. 8. Package outline SOT762-1 (DHVQFN14)

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12. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74ALVC00 v.6	20230704	Product data sheet	-	74ALVC00 v.5	
Modifications:	 Specifications for T_{amb} = -40 °C to +125 °C added. <u>Section 1</u> updated. <u>Section 2</u> updated; ESD specification updated according to the latest JEDEC standard. 				
74ALVC00 v.5	20210430	Product data sheet	-	74ALVC00 v.4	
Modifications:	 Section 2: Reference to JESD36 removed. Table 4: Derating values for P_{tot} total power dissipation updated (errata). 				
74ALVC00 v.4	20200921	Product data sheet	-	74ALVC00 v.3	
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Table 4: Derating values for P_{tot} total power dissipation have been updated. Package outline drawing of SOT762-1 (Fig. 8) updated. 				
74ALVC00 v.3	20140516	Product data sheet	-	74ALVC00 v.2	
	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. 				
74ALVC00 v.2	20030514	Product specification	-	74ALVC00 v.1	
74ALVC00 v.1	20030206	Product specification	-	-	

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14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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